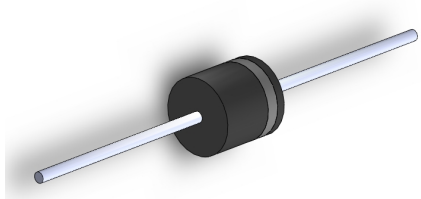
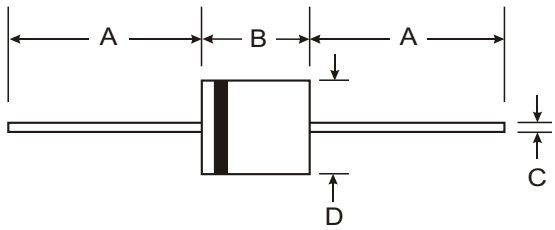
SF61 - SF69

SUPER FAST RECOVERY RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V
CURRENT: 6.0 A





Features

- High current capability
- High surge current capability
- High reliability
- Low reverse current
- Low forward voltage drop
- Super fast recovery time

Mechanical Data

- Case : R-6 molded plastic body
- Epoxy : UL94V-O rate flame retardant
- Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
- Polarity : Color band denotes cathode end
- Mounting position : Any
- Weight : 2.1 grams

RoHS COMPLIANT

R-6		
Dim	**Min**	**Max**
A	25.4	—
B	8.6	9.1
C	1.2	1.3
D	8.6	9.1
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics

T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	SYMBOL	SF61	SF62	SF63	SF64	SF65	SF66	SF67	SF68	SF69	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	800	1000	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 55 °C	$I_{F(AV)}$	6.0									A
Maximum Peak Forward Surge Current, 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method)	I_{FSM}	150									A
Maximum Peak Forward Voltage at I_F = 6.0 A.	V_F	0.95				1.7			4.0		V
Maximum DC Reverse Current Ta = 25 °C	I_R	5									µA
at Rated DC Blocking Voltage Ta = 100 °C	$I_{R(H)}$	50									µA
Maximum Reverse Recovery Time (Note 1)	Trr	35									ns
Typical Junction Capacitance (Note 2)	C_J	50									pf
Junction Temperature Range	T_J	- 65 to + 150									°C
Storage Temperature Range	T_{STG}	- 65 to + 150									°C

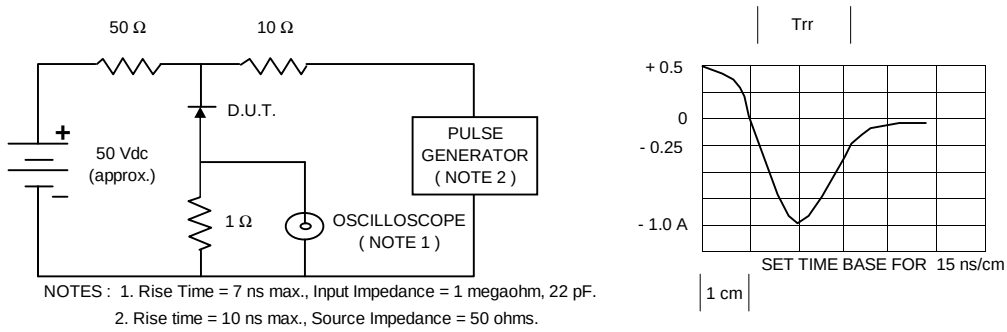
Notes :

(1) Reverse Recovery Test Conditions : I_F = 0.5 A, I_R = 1.0 A, Irr = 0.25 A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 V_{DC}

RATING AND CHARACTERISTIC CURVES (SF61 - SF69)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.
2. Rise time = 10 ns max., Source Impedance = 50 ohms.
3. All Resistors = Non-inductive Types.

FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

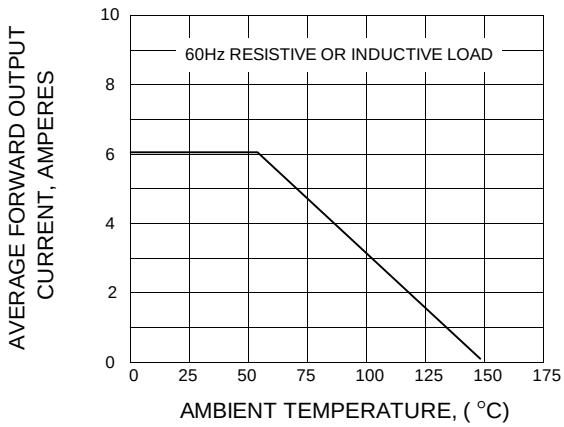


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

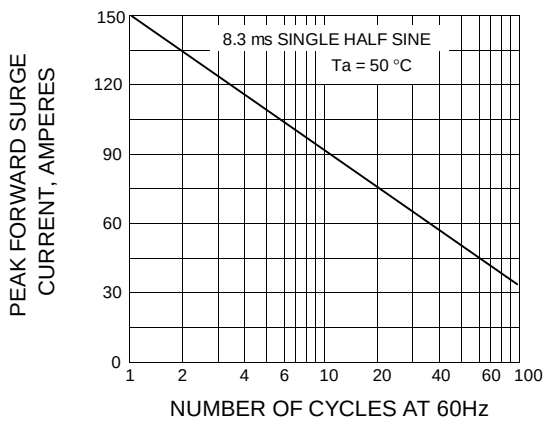


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

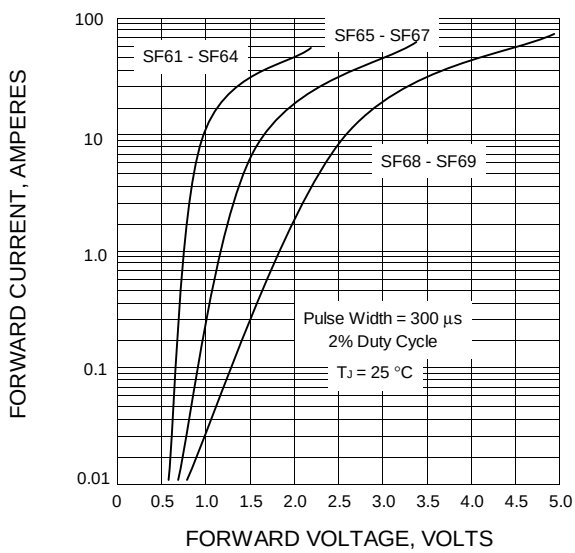


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

